

Zener Voltage Regulators

500 mW SOD-123 Surface Mount

MMSZ52xxET1G Series, SZMMSZ52xxET1G Series

Two complete series of Zener diodes are offered in the convenient, surface mount plastic SOD-123 package. These devices provide a convenient alternative to the leadless 34-package style.

Features

- 500 mW Rating on FR-4 or FR-5 Board
- Wide Zener Reverse Voltage Range – 2.4 V to 110 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- General Purpose, Medium Current
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- Peak Power – 225 W (8 x 20 μs)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available*

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MAXIMUM RATINGS

| Rating | Symbol | Max | Units |
|---|-----------------|----------------|-------------|
| Peak Power Dissipation @ 20 μs (Note 1) @ $T_L \leq 25^\circ\text{C}$ | P_{pk} | 225 | W |
| Total Power Dissipation on FR-5 Board, (Note 3) @ $T_L = 75^\circ\text{C}$ Derated above 75°C | P_D | 500 6.7 | mW mW/°C |
| Thermal Resistance, (Note 2) Junction-to-Ambient | $R_{\theta JA}$ | 340 | °C/W |
| Thermal Resistance, (Note 2) Junction-to-Lead | $R_{\theta JL}$ | 150 | °C/W |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | °C |

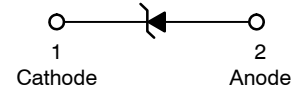
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 11.
2. Thermal Resistance measurement obtained via infrared Scan Method.
3. FR-5 = 3.5 x 1.5 inches, using the minimum recommended footprint.

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



SOD-123
CASE 425
STYLE 1



MARKING DIAGRAM



xxx = Device Code (Refer to page 2)

M = Date Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|----------------------|------------------------|
| MMSZ52xxET1G | SOD-123 (Pb-Free) | 3,000 / Tape & Reel |
| SZMMSZ52xxET1G | SOD-123 (Pb-Free) | 3,000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

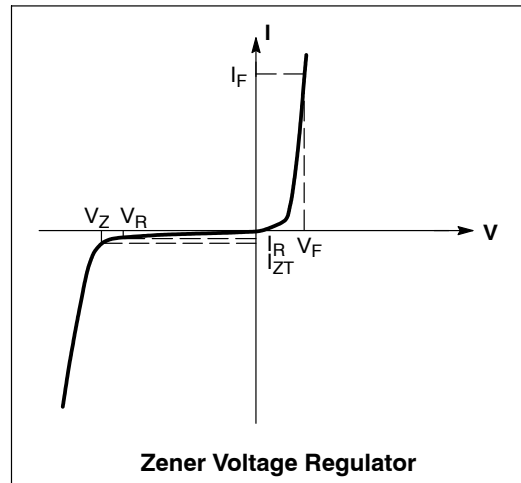
DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

MMSZ52xxET1G Series, SZMMSZ52xxET1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.95\text{ V Max. @ } I_F = 10\text{ mA}$)

| Symbol | Parameter |
|----------|------------------------------------|
| V_Z | Reverse Zener Voltage @ I_{ZT} |
| I_{ZT} | Reverse Current |
| Z_{ZT} | Maximum Zener Impedance @ I_{ZT} |
| I_{ZK} | Reverse Current |
| Z_{ZK} | Maximum Zener Impedance @ I_{ZK} |
| I_R | Reverse Leakage Current @ V_R |
| V_R | Reverse Voltage |
| I_F | Forward Current |
| V_F | Forward Voltage @ I_F |



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.9\text{ V Max. @ } I_F = 10\text{ mA}$)

| Device* | Device Marking | Zener Voltage (Notes 4 and 5) | | | | Zener Impedance (Note 6) | | | Leakage Current | |
|--------------|----------------|-------------------------------|-----|-------|------------|--------------------------|---------------------|------|-----------------|-----|
| | | V_Z (V) | | | @ I_{ZT} | Z_{ZT} @ I_{ZT} | Z_{ZK} @ I_{ZK} | | I_R @ V_R | |
| | | Min | Nom | Max | mA | Ω | Ω | mA | μA | V |
| MMSZ5221ET1G | CA1 | 2.28 | 2.4 | 2.52 | 20 | 30 | 1200 | 0.25 | 100 | 1 |
| MMSZ5223ET1G | CA3 | 2.57 | 2.7 | 2.84 | 20 | 30 | 1300 | 0.25 | 75 | 1 |
| MMSZ5226ET1G | CA6 | 3.14 | 3.3 | 3.47 | 20 | 28 | 1600 | 0.25 | 25 | 1 |
| MMSZ5228ET1G | CA8 | 3.71 | 3.9 | 4.10 | 20 | 23 | 1900 | 0.25 | 10 | 1 |
| MMSZ5229ET1G | CA9 | 4.09 | 4.3 | 4.52 | 20 | 22 | 2000 | 0.25 | 5 | 1 |
| MMSZ5231ET1G | CB2 | 4.85 | 5.1 | 5.36 | 20 | 17 | 1600 | 0.25 | 5 | 2 |
| MMSZ5232ET1G | CB3 | 5.32 | 5.6 | 5.88 | 20 | 11 | 1600 | 0.25 | 5 | 3 |
| MMSZ5234ET1G | CB5 | 5.89 | 6.2 | 6.51 | 20 | 7 | 1000 | 0.25 | 5 | 4 |
| MMSZ5235ET1G | CB6 | 6.46 | 6.8 | 7.14 | 20 | 5 | 750 | 0.25 | 3 | 5 |
| MMSZ5236ET1G | CB7 | 7.13 | 7.5 | 7.88 | 20 | 6 | 500 | 0.25 | 3 | 6 |
| MMSZ5237ET1G | CB8 | 7.79 | 8.2 | 8.61 | 20 | 8 | 500 | 0.25 | 3 | 6.5 |
| MMSZ5240ET1G | CC2 | 9.50 | 10 | 10.50 | 20 | 17 | 600 | 0.25 | 3 | 8 |
| MMSZ5242ET1G | CC4 | 11.40 | 12 | 12.60 | 20 | 30 | 600 | 0.25 | 1 | 9.1 |
| MMSZ5243ET1G | CC5 | 12.35 | 13 | 13.65 | 9.5 | 13 | 600 | 0.25 | 0.5 | 9.9 |
| MMSZ5244ET1G | CC6 | 13.30 | 14 | 14.70 | 9.0 | 15 | 600 | 0.25 | 0.1 | 10 |
| MMSZ5245ET1G | CC7 | 14.25 | 15 | 15.75 | 8.5 | 16 | 600 | 0.25 | 0.1 | 11 |
| MMSZ5246ET1G | CC8 | 15.20 | 16 | 16.80 | 7.8 | 17 | 600 | 0.25 | 0.1 | 12 |
| MMSZ5248ET1G | CD1 | 17.10 | 18 | 18.90 | 7.0 | 21 | 600 | 0.25 | 0.1 | 14 |
| MMSZ5250ET1G | CD3 | 19.00 | 20 | 21.00 | 6.2 | 25 | 600 | 0.25 | 0.1 | 15 |
| MMSZ5252ET1G | CD5 | 22.80 | 24 | 25.20 | 5.2 | 33 | 600 | 0.25 | 0.1 | 18 |

4. The type numbers shown have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage.
5. Nominal Zener voltage is measured with the device junction in thermal equilibrium at $T_L = 30^\circ\text{C} \pm 1^\circ\text{C}$.
6. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the ac current applied. The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(dc)}$ with the AC frequency = 1 kHz.

*Include SZ-prefix devices where applicable

MMSZ52xxET1G Series, SZMMSZ52xxET1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.9\text{ V Max.}$ @ $I_F = 10\text{ mA}$)

| Device* | Device Marking | Zener Voltage (Notes 4 and 5) | | | | Zener Impedance (Note 6) | | | Leakage Current | |
|--------------|----------------|-------------------------------|-----|-------|------------|--------------------------|---------------------|------|-----------------|----|
| | | V_Z (V) | | | @ I_{ZT} | Z_{ZT} @ I_{ZT} | Z_{ZK} @ I_{ZK} | | I_R @ V_R | |
| | | Min | Nom | Max | mA | Ω | Ω | mA | μA | V |
| MMSZ5253ET1G | CD6 | 23.75 | 25 | 26.25 | 5.0 | 35 | 600 | 0.25 | 0.1 | 19 |
| MMSZ5254ET1G | CD7 | 25.65 | 27 | 28.35 | 4.6 | 41 | 600 | 0.25 | 0.1 | 21 |
| MMSZ5255ET1G | CD8 | 26.60 | 28 | 29.40 | 4.5 | 44 | 600 | 0.25 | 0.1 | 21 |
| MMSZ5256ET1G | CD9 | 28.50 | 30 | 31.50 | 4.2 | 49 | 600 | 0.25 | 0.1 | 23 |
| MMSZ5257ET1G | CE1 | 31.35 | 33 | 34.65 | 3.8 | 58 | 700 | 0.25 | 0.1 | 25 |
| MMSZ5258ET1G | CE2 | 34.20 | 36 | 37.80 | 3.4 | 70 | 700 | 0.25 | 0.1 | 27 |
| MMSZ5259ET1G | CE3 | 37.05 | 39 | 40.95 | 3.2 | 80 | 800 | 0.25 | 0.1 | 30 |
| MMSZ5262ET1G | CE6 | 48.45 | 51 | 53.55 | 2.5 | 125 | 1100 | 0.25 | 0.1 | 39 |
| MMSZ5263ET1G | CE7 | 53.20 | 56 | 58.80 | 2.2 | 150 | 1300 | 0.25 | 0.1 | 43 |

4. The type numbers shown have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage.

5. Nominal Zener voltage is measured with the device junction in thermal equilibrium at $T_L = 30^\circ\text{C} \pm 1^\circ\text{C}$.

6. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the ac current applied.

The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(dc)}$ with the AC frequency = 1 kHz.

*Include SZ-prefix devices where applicable

MMSZ52xxET1G Series, SZMMSZ52xxET1G Series

TYPICAL CHARACTERISTICS

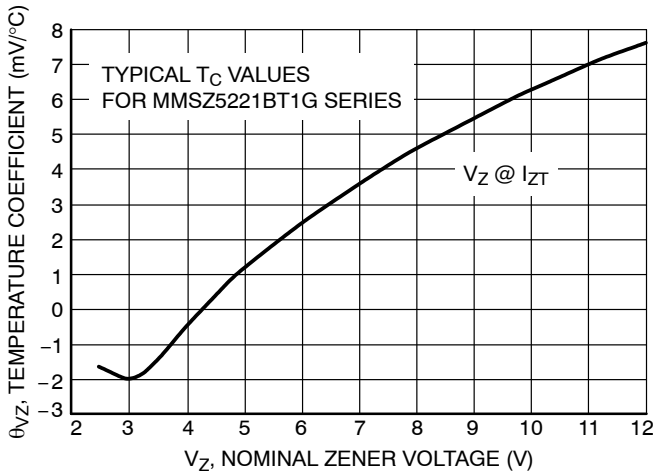


Figure 1. Temperature Coefficients (Temperature Range -55°C to +150°C)

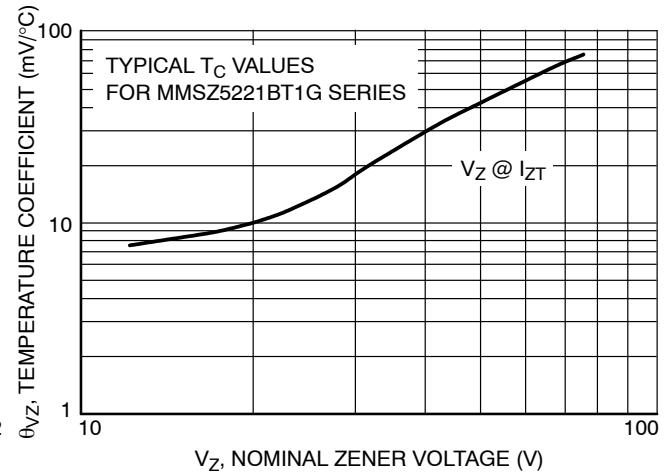


Figure 2. Temperature Coefficients (Temperature Range -55°C to +150°C)

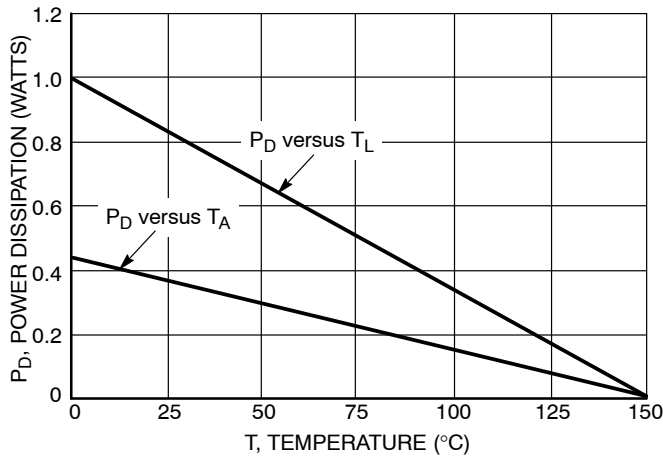


Figure 3. Steady State Power Derating

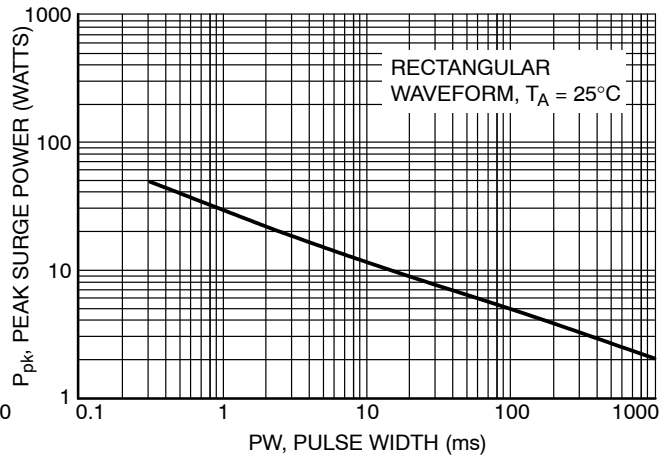


Figure 4. Maximum Nonrepetitive Surge Power

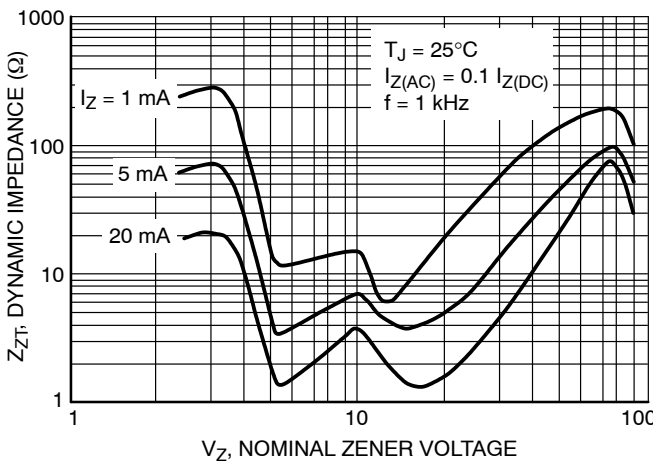


Figure 5. Effect of Zener Voltage on Zener Impedance

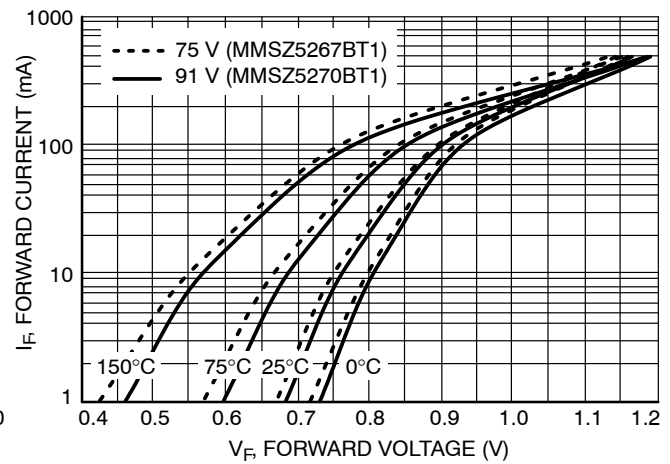


Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

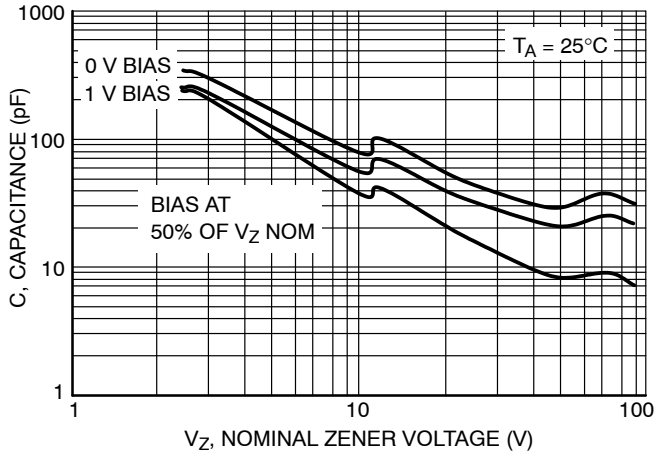


Figure 7. Typical Capacitance

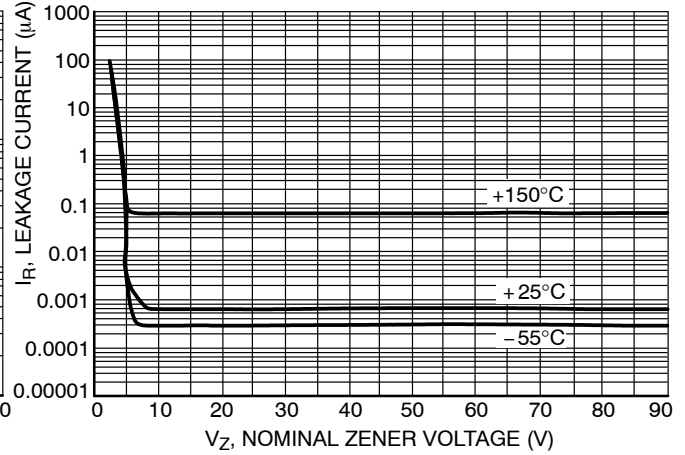


Figure 8. Typical Leakage Current

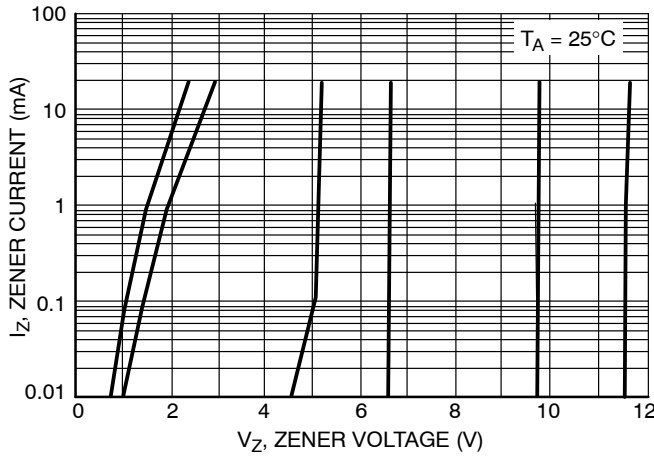


Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

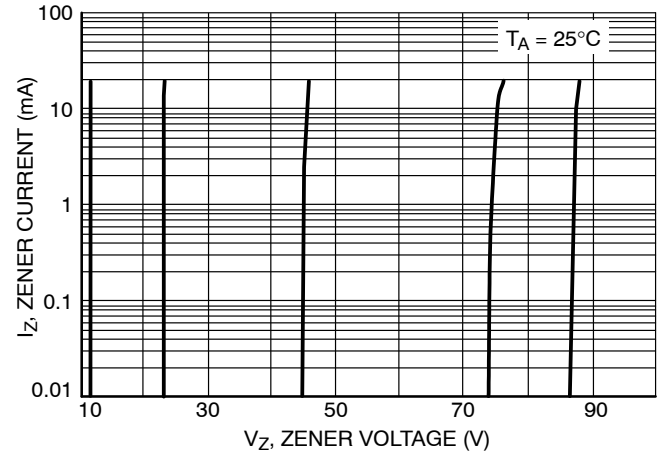


Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

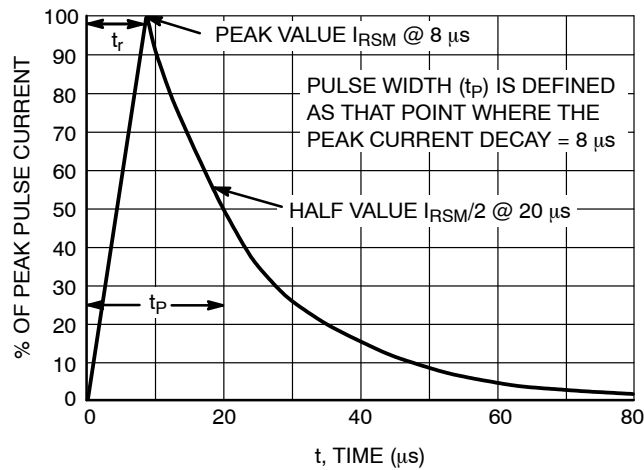
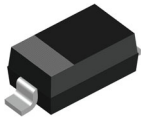
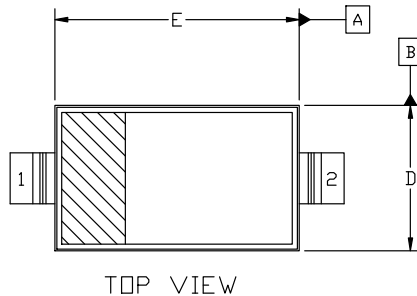


Figure 11. 8 × 20 µs Pulse Waveform

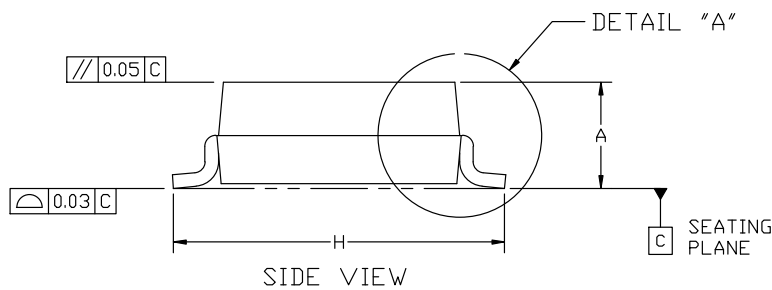


SOD-123 2-LEAD, 1.60x2.69x1.16
CASE 425
ISSUE H

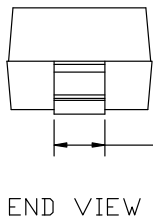
DATE 29 FEB 2024



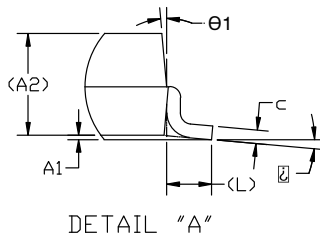
TOP VIEW



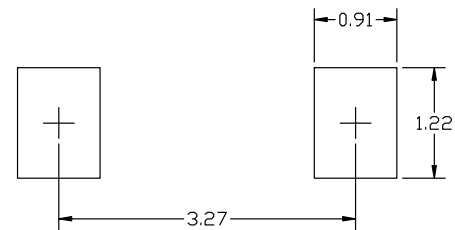
SIDE VIEW



END VIEW



DETAIL "A"



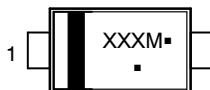
RECOMMENDED MOUNTING FOOTPRINT
*For additional information on or Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual SOLDERM/D.

NOTES:

1. DIMENSION AND TOLERANCING PER ASME Y14.5M, 2018
2. CONTROLLING DIMENSION: MILLIMETERS

| DIM | MILLIMETER | | |
|-----|------------|------|------|
| | MIN. | NDM. | MAX. |
| A | 0.94 | 1.17 | 1.35 |
| A1 | 0.00 | 0.05 | 0.10 |
| A2 | 1.16 REF. | | |
| b | 0.51 | 0.61 | 0.71 |
| c | - | - | 0.15 |
| D | 1.40 | 1.60 | 1.80 |
| E | 2.54 | 2.69 | 2.84 |
| H | 3.56 | 3.68 | 3.86 |
| L | 0.25 REF. | | |
| ∠ | 0° | | 10° |
| θ1 | 0° | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. CATHODE
2. ANODE

| | | |
|------------------|--------------------------------|--|
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| DESCRIPTION: | SOD-123 2-LEAD, 1.60x2.69x1.16 | PAGE 1 OF 1 |

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